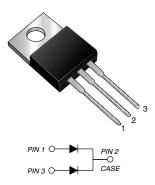


Vishay General Semiconductor

Dual Common-Cathode High Voltage Schottky Rectifier

TMBS® TO-220AB



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5.0 A			
V _{RRM}	90 V, 100 V			
I _{FSM}	120 A			
V_{F}	0.75 V			
T _J max.	150 °C			

FEATURES

- · Trench MOS Schottky technology
- · Lower power losses, high efficiency
- · Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- · Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, converters or polarity protection application

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability

Base P/N-E3 - RoHS compliant, commercial grade Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR1090CT	MBR10100CT	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V		
Working peak reverse voltage	V _{RWM}	90	100	V		
Maximum DC blocking voltage	V _{DC}	90	100	V		
Maximum average forward rectified current at T _C = 105 °C total device per diode	I _{F(AV)}	10 5.0		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	120		Α		
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH per diode	E _{AS}	6	60	mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode	I _{RRM}	0.5		Α		
Voltage rate of change (rated V _R)	dV/dt	10	000	V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to	+ 150	°C		

MBR1090CT, MBR10100CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1090CT	MBR10100CT	UNIT
Maximum instantaneous forward voltage per diode (1)	I _F = 5.0 A I _F = 5.0 A	T _C = 125 °C T _C = 25 °C	V _F	0.75 0.85		٧
Maximum reverse current per diode at working peak reverse voltage (2)		T _J = 25 °C T _J = 100 °C	I _R		00 .0	μA mA

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR1090CT MBR10100CT		UNIT	
Typical thermal resistance per diode	$R_{ hetaJC}$	4.4		°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR10100CT-E3/4W	1.87	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

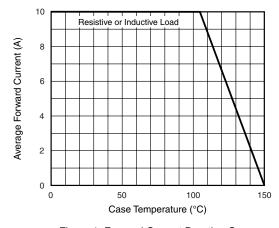


Figure 1. Forward Current Derating Curve

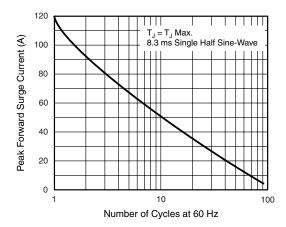


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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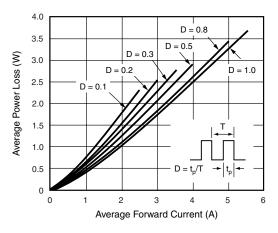


Figure 3. Forward Power Loss Characteristics Per Diode

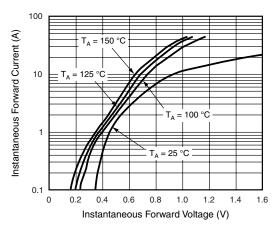


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

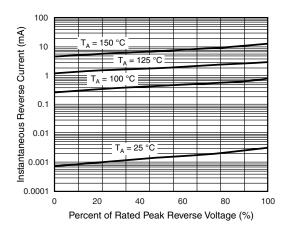


Figure 5. Typical Reverse Characteristics Per Diode

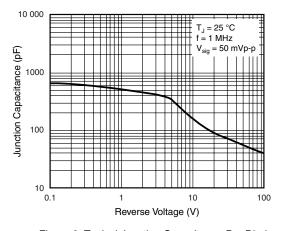


Figure 6. Typical Junction Capacitance Per Diode

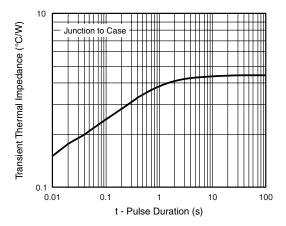


Figure 7. Typical Transient Thermal Impedance Per Diode

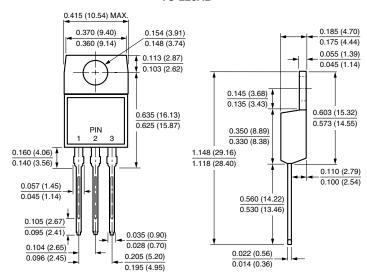
MBR1090CT, MBR10100CT

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB





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